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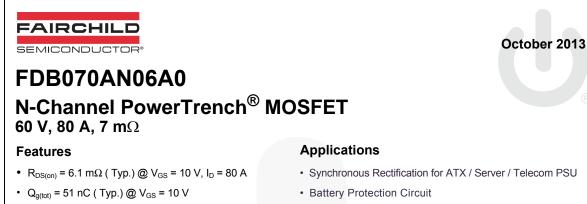


ON Semiconductor®

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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

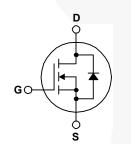
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- Low Miller Charge
 Low Q_{rr} Body Diode
- UIS Capability (Single Pulse and Repetitive Pulse)

Formerly developmental type 82567

G S D²-PAK



Motor Drives and Uninterruptible Power Supplies

MOSFET Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	FDB070AN06A0	Unit
V _{DSS}	Drain to Source Voltage	60	V
V _{GS}	Gate to Source Voltage	±20	V
	Drain Current		
I _D	Continuous ($T_C < 97^{\circ}C$, $V_{GS} = 10V$)	80	Α
	Continuous (T _A = 25°C, V _{GS} = 10V, $R_{\theta JA}$ = 43°C/W)	15	A
	Pulsed	Figure 4	A
E _{AS}	Single Pulse Avalanche Energy (Note 1)	190	mJ
P _D	Power dissipation	175	W
	Derate above 25°C	1.17	W/ºC
T _J , T _{STG}	Operating and Storage Temperature	-55 to 175	°C

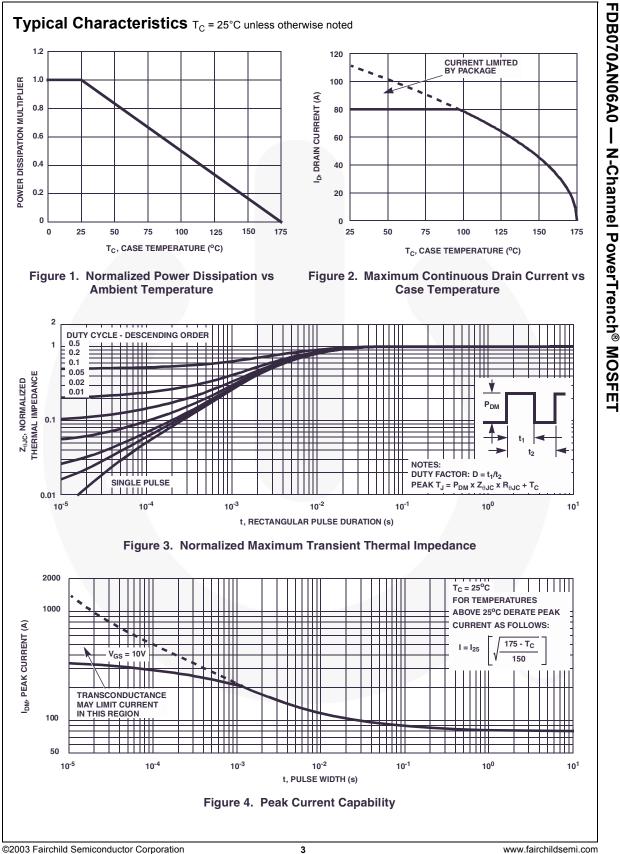
Thermal Characteristics

$R_{ extsf{ heta}JC}$	Thermal Resistance Junction to Case, Max.	0.86	°C/W
R_{\thetaJA}	Thermal Resistance Junction to Ambient, Max. (Note 2)	62	°C/W
R_{\thetaJA}	Thermal Resistance Junction to Ambient, Max., 1in ² copper pad area	43	°C/W

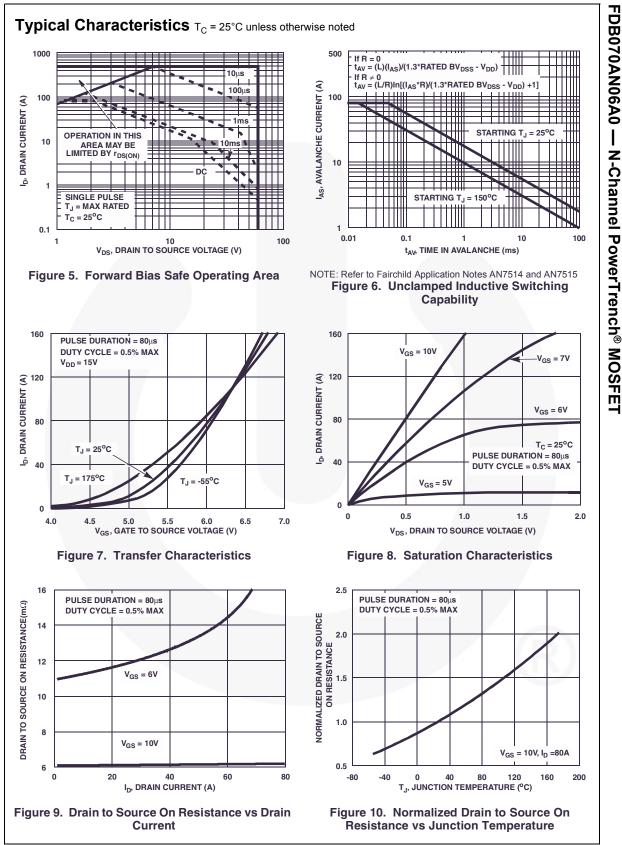
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Device	Marking	Device Package Reel Size		Tape Width 24 mm		Quar	ntity				
FDB070AN06A0		FDB070AN06A0	D ² -PAK 330 mm			800 units					
Electrical Characteristics T _C = 25°C unless otherwise noted											
Symbol		Parameter	Test	Conditions	Min	Тур	Мах	Unit			
Off Chara	acteristics	6									
B _{VDSS}		ource Breakdown Voltage	I _D = 250μA,	$V_{GS} = 0V$	60	-	-	V			
		•	V _{DS} = 50V	00	-	-	1				
I _{DSS}	Zero Gate Voltage Drain Current		$V_{GS} = 0V$	T _C = 150 ^o C	-	-	250	μA			
I _{GSS}	Gate to Source Leakage Current		V _{GS} = ±20V		-	-	±100	nA			
On Chara	cteristics										
V _{GS(TH)}	Gate to Source Threshold Voltage		$V_{GS} = V_{DS},$	I _D = 250μA	2	-	4	V			
33(11)			I _D = 80A, V _C	-	-	0.0061	0.007				
r _{DS(ON)}	Drain to Source On Resistance		$I_D = 80A, V_C$ $T_1 = 175^{\circ}C$		-	0.0127	0.015	Ω			
Dynamic	Characte	ristics				1		1			
C _{ISS}	Input Capa				-	3000	-	pF			
C _{OSS}	Output Ca		$V_{DS} = 25V,$	$V_{GS} = 0V,$	-	510	-	pF			
C _{RSS}	Reverse T	ransfer Capacitance	f = 1MHz		-	230	-	pF			
Q _{g(TOT)}	Total Gate	Charge at 10V	V _{GS} = 0V to	10V		51	66	nC			
Q _{g(TH)}	Threshold	Gate Charge		2V _{VDD} = 30V	-	5.4	7	nC			
Q _{gs}	Gate to So	ource Gate Charge		I _D = 80A	-	17	-	nC			
Q _{gs2}	Gate Char	ge Threshold to Plateau		I _g = 1.0mA	-	11.6	-	nC			
Q _{gd}	Gate to Dr	ain "Miller" Charge			-	16	-	nC			
Switching	g Charact	eristics (V _{GS} = 10V)									
t _{ON}	Turn-On T				- /	-	256	ns			
t _{d(ON)}	Turn-On D	elay Time			-	12	-	ns			
t _r	Rise Time		V _{DD} = 30V, I	_D = 80A		159	-	ns			
t _{d(OFF)}	Turn-Off D	elay Time	V _{DD} = 30V, 1 V _{GS} = 10V,	R _{GS} = 5.6Ω	-	27	-	ns			
t _f	Fall Time					35	-	ns			
t _{OFF}	Turn-Off T	ime					93	ns			
	urce Diod	e Characteristics									
V.	Source to	Drain Diodo Valtago	I _{SD} = 80A		-	-	1.25	V			
V _{SD}	Source to Drain Diode Voltage	Drain Dioue voltage	I _{SD} = 40A		-	-	1.0	V			
t _{rr}	_	ecovery Time	-	ll _{SD} /dt = 100A/μs		-	34	ns			
Q _{RR}	Reverse R	ecovered Charge	I_{SD} = 75A, dI_{SD}/dt = 100A/µs		-	-	35	nC			

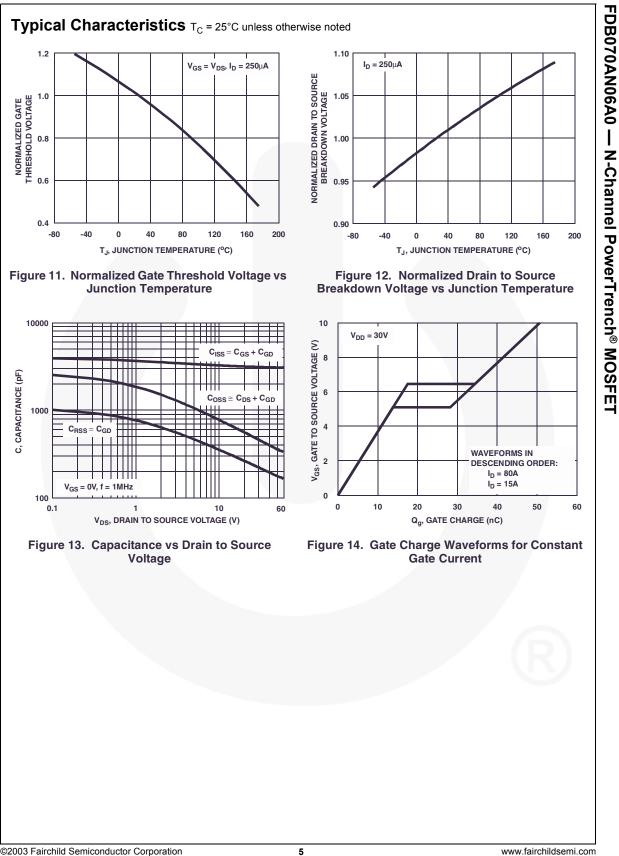
FDB070AN06A0 — N-Channel PowerTrench® MOSFET

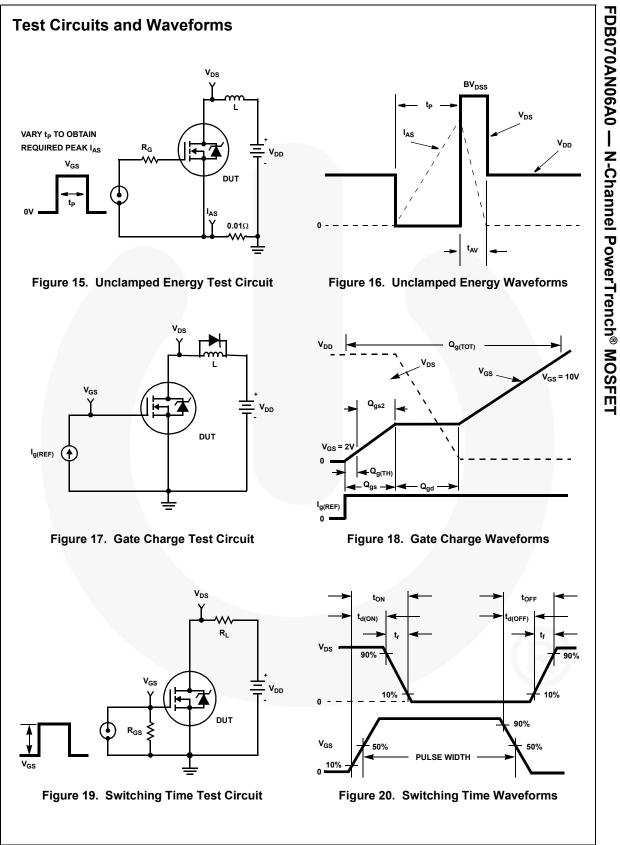


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Thermal Resistance vs. Mounting Pad Area

The maximum rated junction temperature, T_{JM} , and the thermal resistance of the heat dissipating path determines the maximum allowable device power dissipation, P_{DM} , in an application. Therefore the application's ambient temperature, T_A (°C), and thermal resistance $R_{\theta JA}$ (°C/W) must be reviewed to ensure that T_{JM} is never exceeded. Equation 1 mathematically represents the relationship and serves as the basis for establishing the rating of the part.

$$P_{DM} = \frac{(T_{JM} - T_A)}{R_{\theta JA}}$$
(EQ. 1)

In using surface mount devices such as the TO-263 package, the environment in which it is applied will have a significant influence on the part's current and maximum power dissipation ratings. Precise determination of P_{DM} is complex and influenced by many factors:

- Mounting pad area onto which the device is attached and whether there is copper on one side or both sides of the board.
- 2. The number of copper layers and the thickness of the board.
- 3. The use of external heat sinks.
- 4. The use of thermal vias.
- 5. Air flow and board orientation.
- 6. For non steady state applications, the pulse width, the duty cycle and the transient thermal response of the part, the board and the environment they are in.

Fairchild provides thermal information to assist the designer's preliminary application evaluation. Figure 21 defines the $R_{\theta JA}$ for the device as a function of the top copper (component side) area. This is for a horizontally positioned FR-4 board with 1oz copper after 1000 seconds of steady state power with no air flow. This graph provides the necessary information for calculation of the steady state junction temperature or power dissipation. Pulse applications can be evaluated using the Fairchild device Spice thermal model or manually utilizing the normalized maximum transient thermal impedance curve.

Thermal resistances corresponding to other copper areas can be obtained from Figure 21 or by calculation using Equation 2 or 3. Equation 2 is used for copper area defined in inches square and equation 3 is for area in centimeters square. The area, in square inches or square centimeters is the top copper area including the gate and source pads.

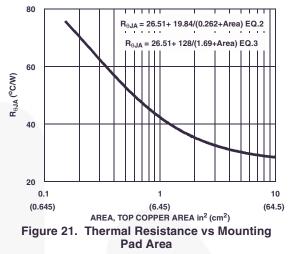
$$R_{\theta JA} = 26.51 + \frac{19.84}{(0.262 + Area)}$$
 (EQ. 2)

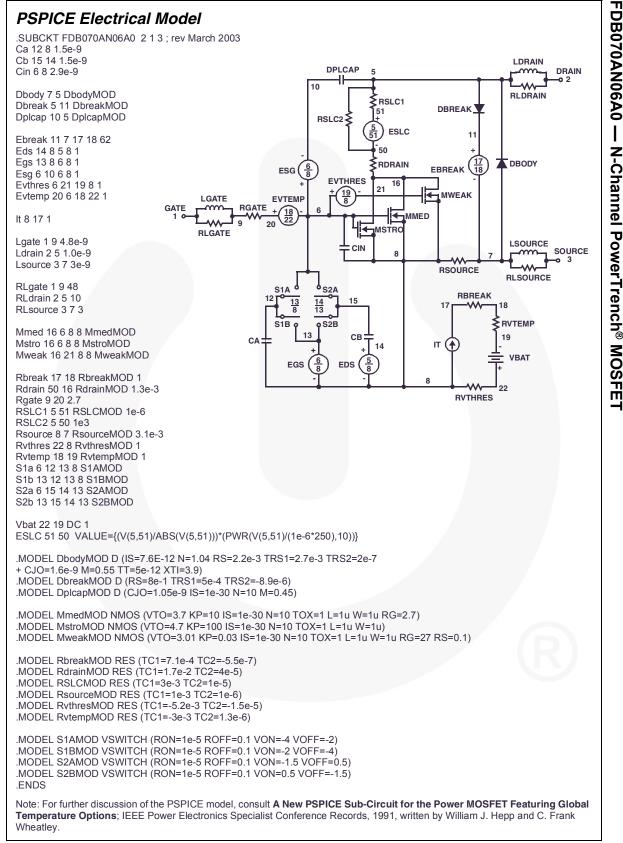
Area in Inches Squared

$$R_{\theta JA} = 26.51 + \frac{128}{(1.69 + Area)}$$
(EQ. 3)

Area in Centimeters Squared

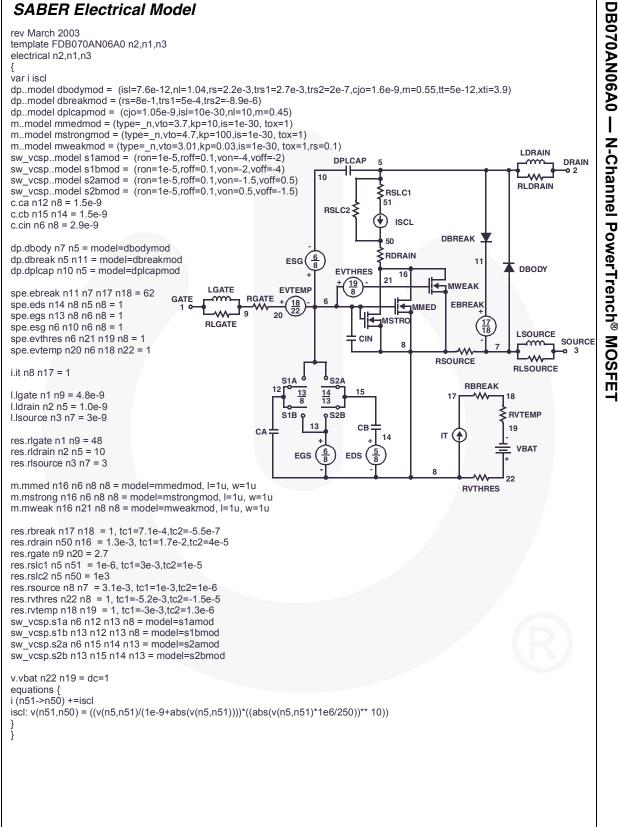
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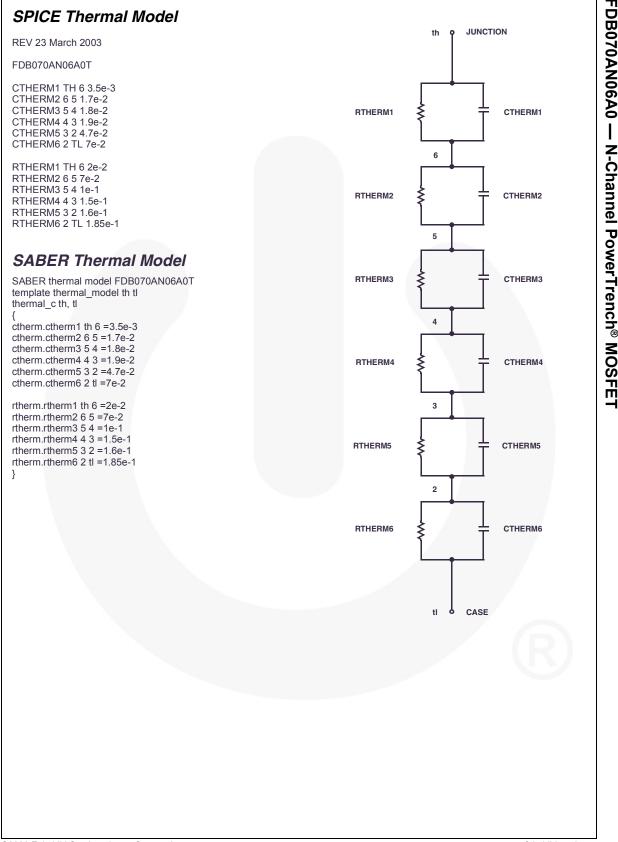


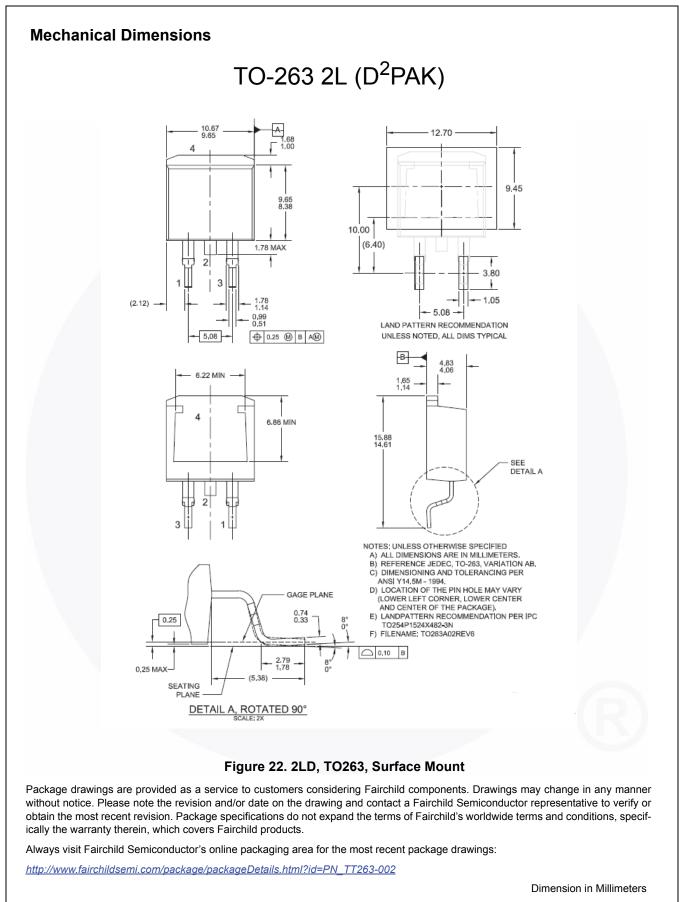


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SABER Electrical Model









Not In Production

Obsolete

Datasheet contains specifications on a product that is discontinued by Fairchild

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Rev 166

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